

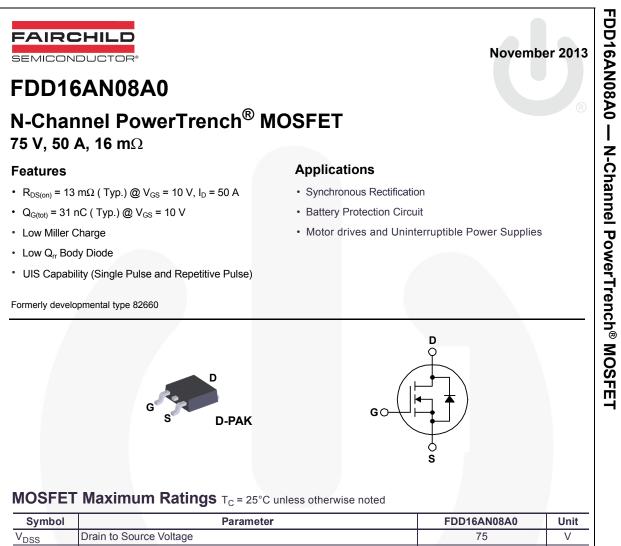
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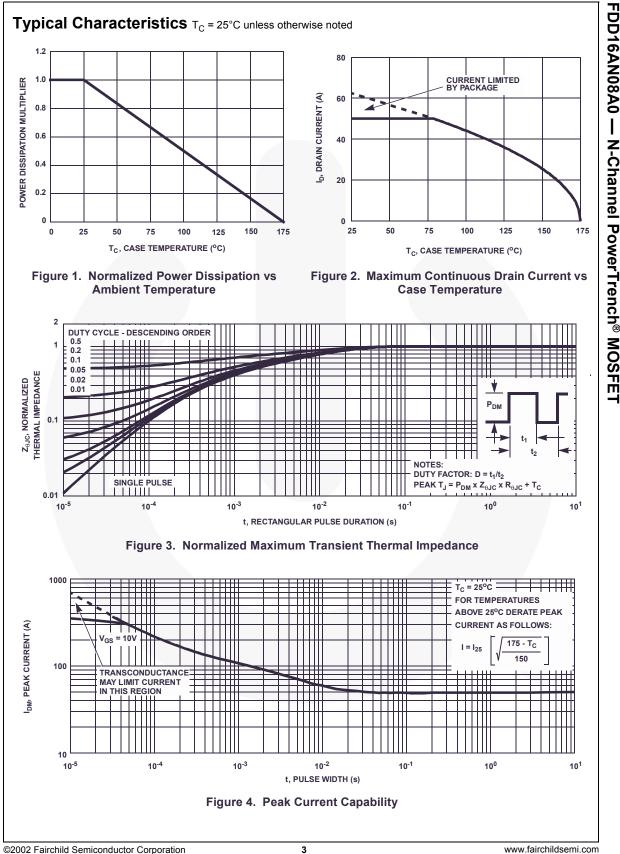
Symbol	Parameter	FDD16AN08A0	Unit	
V <sub>DSS</sub>	Drain to Source Voltage	75	V	
V <sub>GS</sub>	Gate to Source Voltage	±20	V	
	Drain Current			
1	Continuous ( $T_C < 79^{\circ}C$ , $V_{GS} = 10V$ )	50	А	
I <sub>D</sub>	Continuous ( $T_{amb}$ = 25°C, $V_{GS}$ = 10V, with $R_{\theta JA}$ = 52°C/W)	9	А	
	Pulsed	Figure 4	А	
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	95	mJ	
P <sub>D</sub>	Power dissipation	135	W	
	Derate above 25°C	0.9	W/°C	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	-55 to 175	°C	

### **Thermal Characteristics**

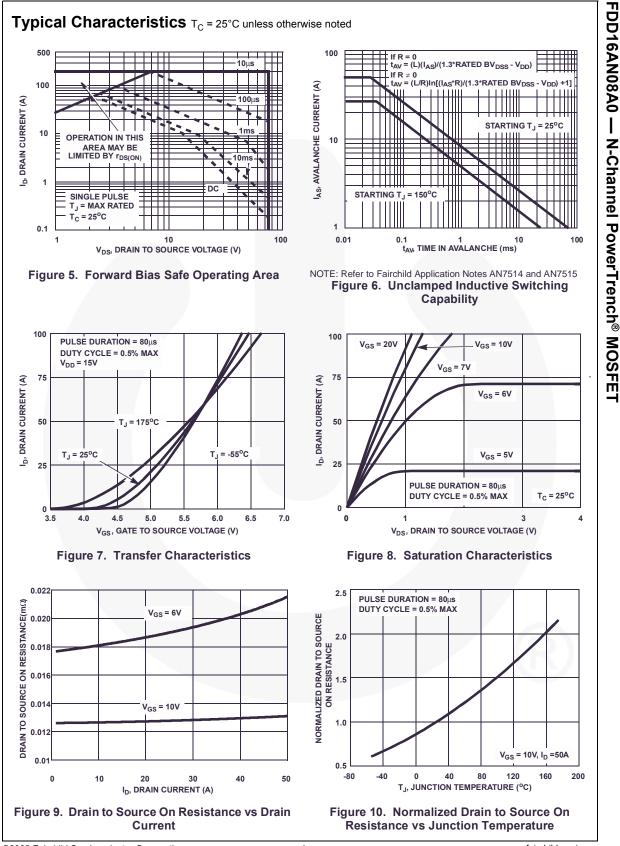
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	1.11	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, 1in <sup>2</sup> copper pad area, Max.	52	°C/W	

		Device Marking Device		Package Reel Size		Vidth	Quar	ntity
	FDD16AN08A0 FDD16AN08A0		D-PAK 330 mm		16 mm		2500 units	
Electric	al Char	acteristics T <sub>c</sub> = 25°C	cunless otherwis	e noted				
Symbol		Parameter	Test	Conditions	Min	Тур	Max	Unit
Off Chara	cteristic	6						
B <sub>VDSS</sub>	Drain to S	ource Breakdown Voltage	I <sub>D</sub> = 250μA, V	$V_{GS} = 0V$	75	-	-	V
	Zana Oata	$V_{\rm DC} = 60V$			-	-	1	
IDSS	Zero Gale	Voltage Drain Current	$V_{GS} = 0V$	$T_{\rm C} = 150^{\rm o}{\rm C}$	-	-	250	μA
I <sub>GSS</sub>	Gate to So	ource Leakage Current	V <sub>GS</sub> = ±20V		-	-	±100	nA
On Chara	cteristics	5						
V <sub>GS(TH)</sub>	1	ource Threshold Voltage	V <sub>GS</sub> = V <sub>DS</sub> , I	_ = 250μA	2	-	4	V
00(11)		0*	I <sub>D</sub> = 50A, V <sub>G</sub>		-	0.013	0.016	
	Desir to C		$I_{\rm D} = 25$ A, V <sub>G</sub>		-	0.019	0.029	
r <sub>DS(ON)</sub>	Drain to Source On Resistance		I <sub>D</sub> = 50A, V <sub>G</sub> T <sub>J</sub> = 175 <sup>o</sup> C	-	-	0.032	0.037	Ω
Dynamic	Characte	eristics	1.3			1		I
C <sub>ISS</sub>	Input Cap				- 1	1874	-	pF
C <sub>OSS</sub>	Output Ca		$V_{DS} = 25V, V$	/ <sub>GS</sub> = 0V,	-	290	-	pF
C <sub>RSS</sub>	-	ransfer Capacitance	f = 1MHz		-	91	-	pF
Q <sub>g(TOT)</sub>	-	Charge at 10V	V <sub>GS</sub> = 0V to	10V		31	47	nC
$Q_{g(TH)}$	-	Gate Charge		2V <sub>VDD</sub> = 40V	-	4	6	nC
Q <sub>qs</sub>	-	ource Gate Charge	00	$I_{\rm D} = 50A$	-	9.7	-	nC
Q <sub>qs2</sub>	-	rge Threshold to Plateau		$I_{g} = 1.0 mA$	-	5.7	-	nC
Q <sub>gd</sub>		rain "Miller" Charge		0	-	7.2	-	nC
Switching	Charact	teristics (V <sub>GS</sub> = 10V)						
t <sub>ON</sub>	Turn-On T				- 1	-	93	ns
t <sub>d(ON)</sub>	Turn-On D	elay Time			-	8	-	ns
t <sub>r</sub>	Rise Time		V <sub>DD</sub> = 40V, I	n = 50A	-	54	-	ns
t <sub>d(OFF)</sub>	Turn-Off D	elay Time	V <sub>GS</sub> = 10V, F		-	32	-	ns
t <sub>f</sub>	Fall Time				-	22	-	ns
t <sub>OFF</sub>	Turn-Off T	ïme	_		-	-	81	ns
	urce Dioc	le Characteristics	1					
			I <sub>SD</sub> = 50A		-	- 1	1.25	V
V <sub>SD</sub>	Source to	Drain Diode Voltage	I <sub>SD</sub> = 25A		-	-	1.0	V
t <sub>rr</sub>	Reverse F	Recovery Time	I <sub>SD</sub> = 50A, dI <sub>SD</sub> /dt = 100A/μs		-	-	34	ns
Q <sub>RR</sub>	Reverse F	Recovered Charge	I <sub>SD</sub> = 50A, d	l <sub>SD</sub> /dt = 100A/μs	-	-	31	nC

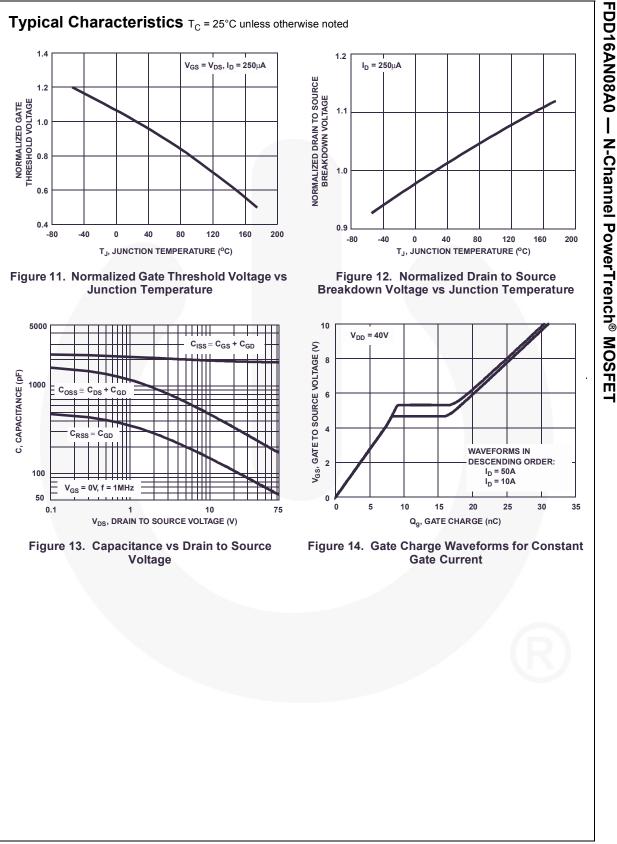
FDD16AN08A0 — N-Channel PowerTrench® MOSFET

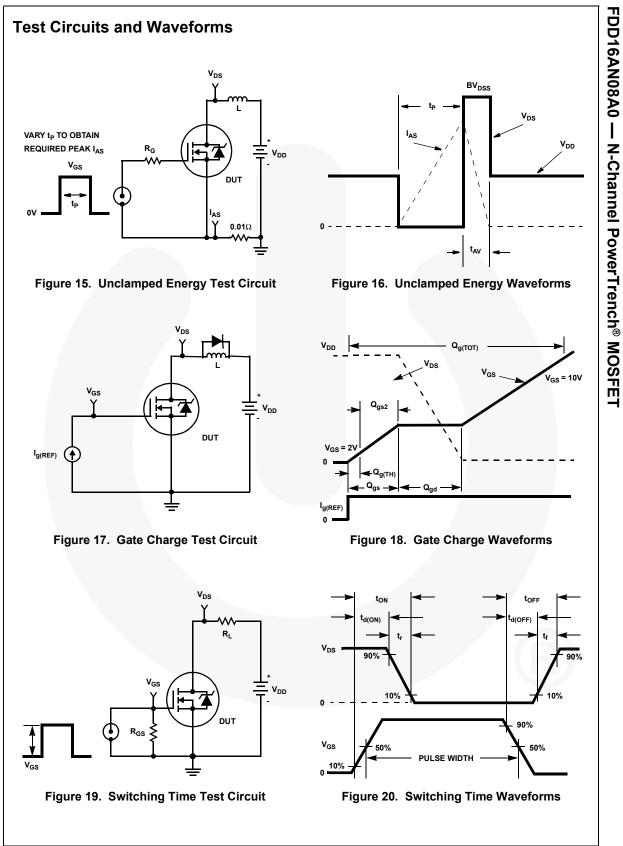


FDD16AN08A0 Rev. C2



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### Thermal Resistance vs. Mounting Pad Area

The maximum rated junction temperature,  $T_{JM}$ , and the thermal resistance of the heat dissipating path determines the maximum allowable device power dissipation,  $P_{DM}$ , in an application. Therefore the application's ambient temperature,  $T_A$  (°C), and thermal resistance  $R_{\theta JA}$  (°C/W) must be reviewed to ensure that  $T_{JM}$  is never exceeded. Equation 1 mathematically represents the relationship and serves as the basis for establishing the rating of the part.

$$P_{DM} = \frac{(T_{JM} - T_A)}{R_{\theta JA}}$$
(EQ. 1)

In using surface mount devices such as the TO-252 package, the environment in which it is applied will have a significant influence on the part's current and maximum power dissipation ratings. Precise determination of  $P_{DM}$  is complex and influenced by many factors:

- Mounting pad area onto which the device is attached and whether there is copper on one side or both sides of the board.
- 2. The number of copper layers and the thickness of the board.
- 3. The use of external heat sinks.
- 4. The use of thermal vias.
- 5. Air flow and board orientation.
- 6. For non steady state applications, the pulse width, the duty cycle and the transient thermal response of the part, the board and the environment they are in.

Fairchild provides thermal information to assist the designer's preliminary application evaluation. Figure 21 defines the  $R_{\theta JA}$  for the device as a function of the top copper (component side) area. This is for a horizontally positioned FR-4 board with 10z copper after 1000 seconds of steady state power with no air flow. This graph provides the necessary information for calculation of the steady state junction temperature or power dissipation. Pulse applications can be evaluated using the Fairchild device Spice thermal model or manually utilizing the normalized maximum transient thermal impedance curve.

Thermal resistances corresponding to other copper areas can be obtained from Figure 21 or by calculation using Equation 2 or 3. Equation 2 is used for copper area defined in inches square and equation 3 is for area in centimeters square. The area, in square inches or square centimeters is the top copper area including the gate and source pads.

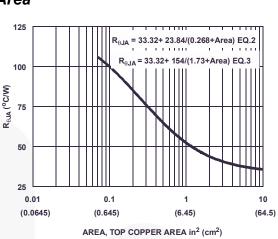
$$R_{\theta JA} = 33.32 + \frac{23.84}{(0.268 + Area)}$$
 (EQ. 2)

Area in Inches Squared

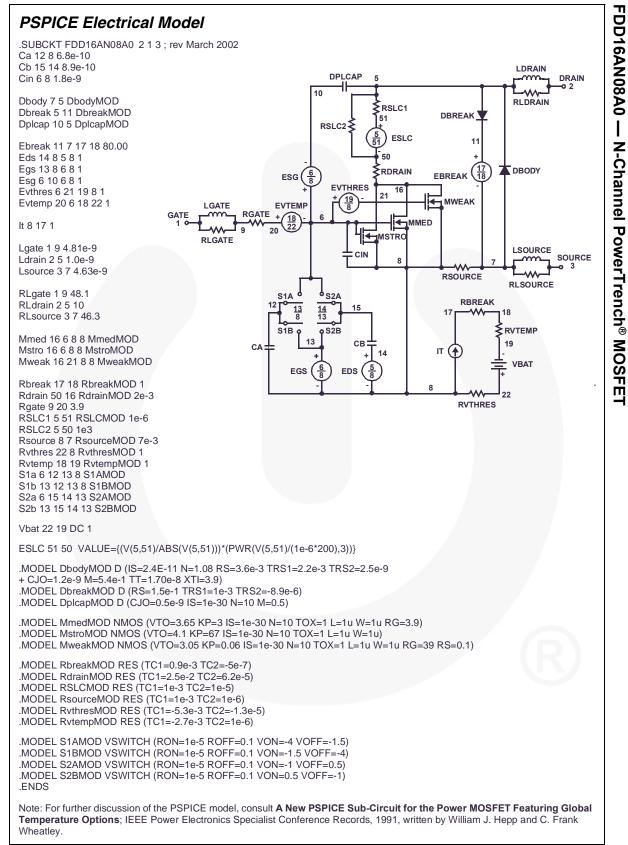
$$R_{\theta JA} = 33.32 + \frac{154}{(1.73 + Area)}$$
(EQ. 3)

Area in Centimeters Squared

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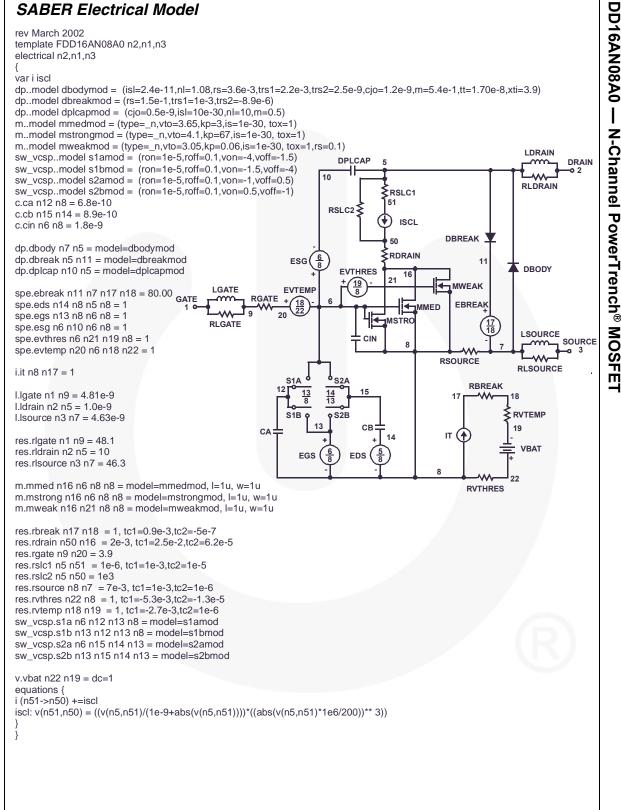


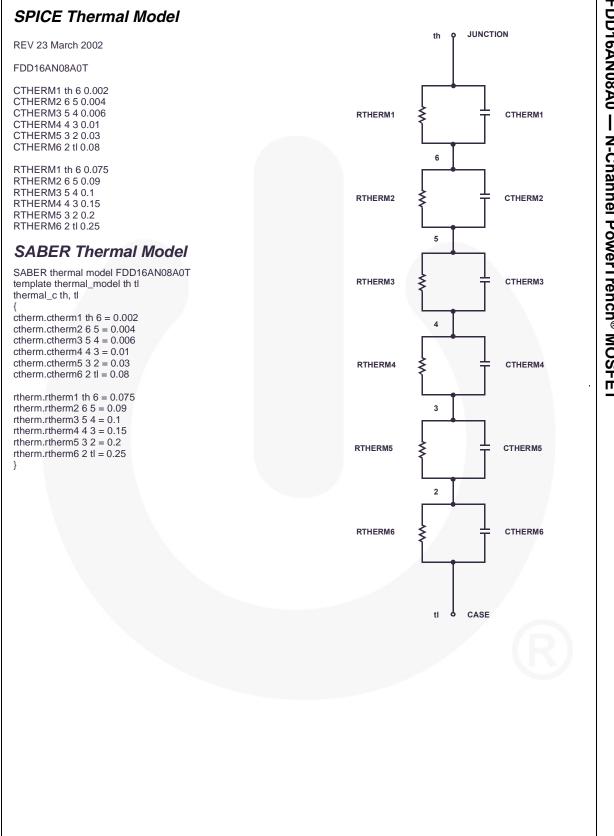




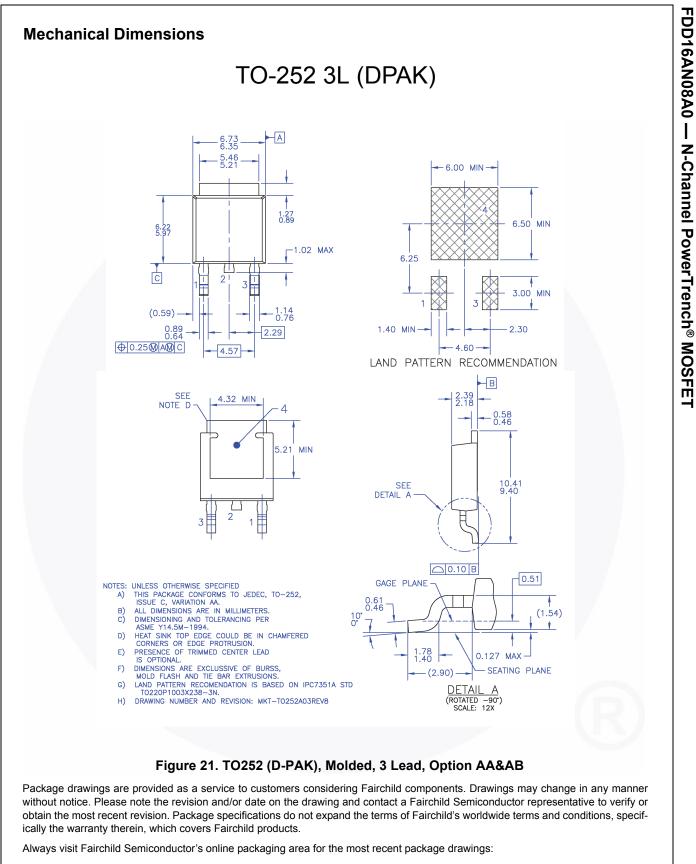
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## SABER Electrical Model





# FDD16AN08A0 — N-Channel PowerTrench<sup>®</sup> MOSFET



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**Dimension in Millimeters** 



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